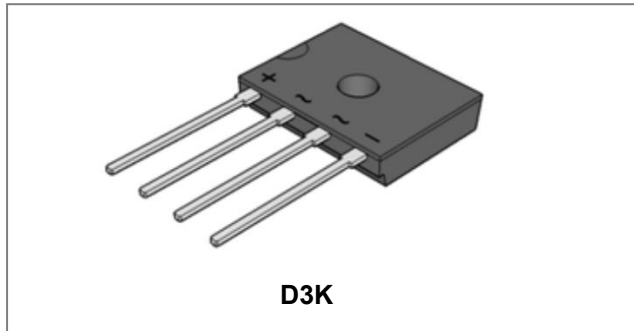


UG4KB05 THRU UG4KB100

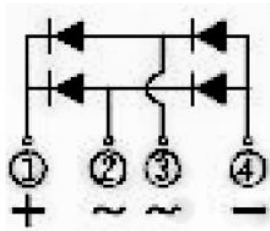
Single-Phase 4.0A Glass Passivated Bridge Rectifier



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: D3K, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

Maximum Ratings: @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	UG4K B05	UG4K B10	UG4K B20	UG4K B40	UG4K B60	UG4K B80	UG4K B100	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average Rectified Output Current Without heat sink @T _A = 30°C Output Current With heat sink @T _A = 140°C	I_O	2.0 4.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	120							A

Electrical Characteristics:

Type Number	Symbol	UG4K B05	UG4K B10	UG4K B20	UG4K B40	UG4K B60	UG4K B80	UG4K B100	Units
Forward Voltage (per element) * @ $I_F = 4.0A$	V_F	1.1							V
Peak Reverse Current * @ $T_A = 25^\circ C$ At Rated DC Blocking Voltage * @ $T_A = 125^\circ C$	I_R	5.0 500							μA
Typical Junction Capacitance(per leg) (Note 1)	C_J	21							pF

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Type Number	Symbol	UG4K B05	UG4K B10	UG4K B20	UG4K B40	UG4K B60	UG4K B80	UG4K B100	Units
Typical Thermal Resistance (per leg)(Note 2)	$R_{\theta JA}$ $R_{\theta JL}$	55 15							$^\circ C/W$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150							$^\circ C$

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
2. Mounted on glass epoxy PC board with 1.3mm² solder pad.

Ratings and Characteristics Curves

Fig. 1 Output Current Derating Curve

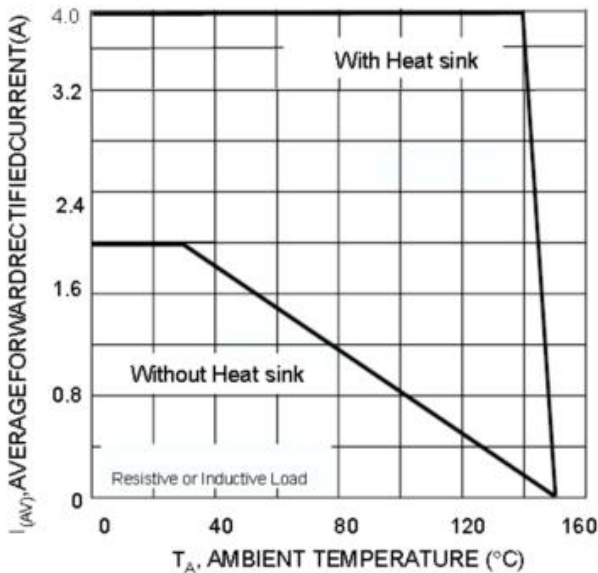


Fig. 2 Typical I Forward Characteristics (per leg)

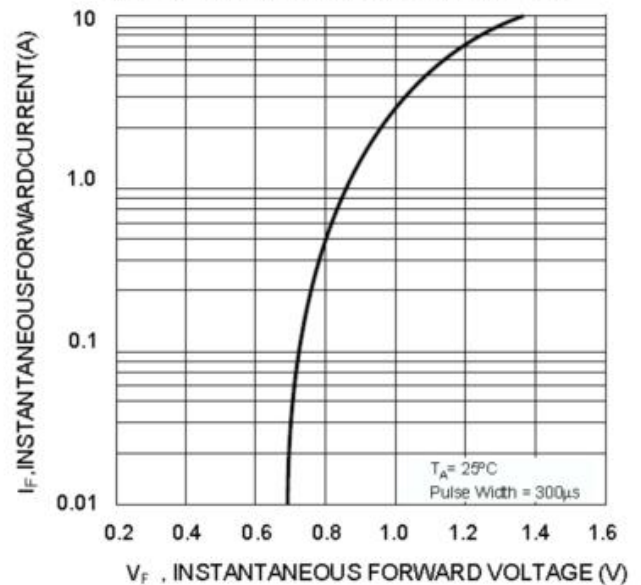


Fig. 3 Maximum Peak Forward Surge Current (per leg)

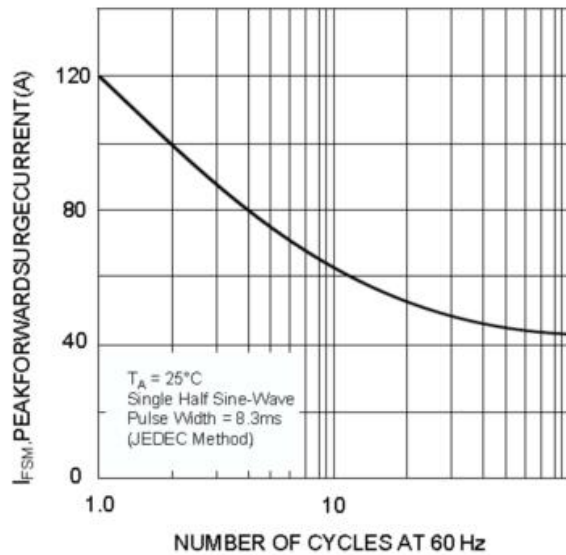


Fig.4 Typical Junction Capacitance Per Diode

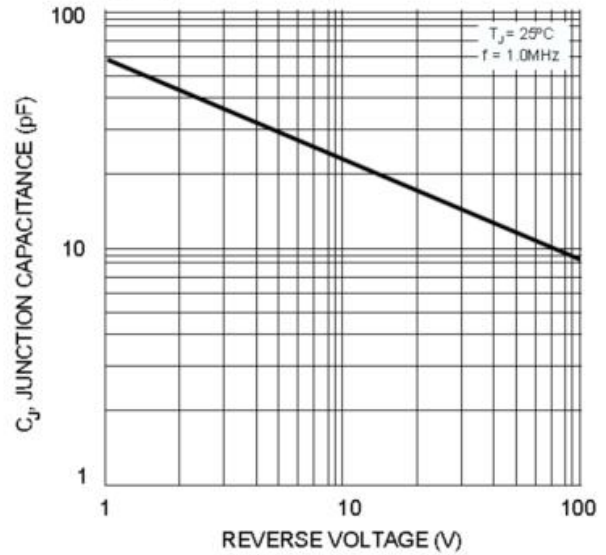
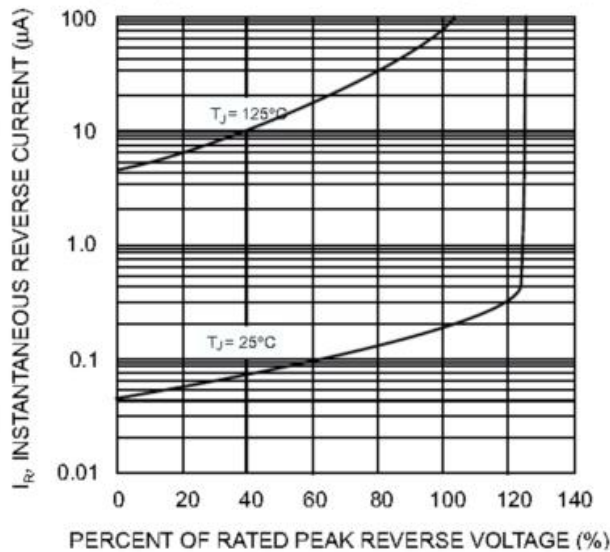


Fig. 5 Typical Reverse Characteristics (per element)

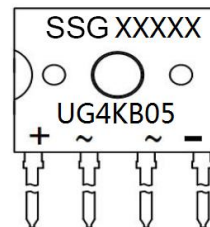


Ordering Information

Device	Package	Plating	Shipping
UG4KB05 THRU UG4KB100	D3K(Pb-Free)	Pure Sn	37pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

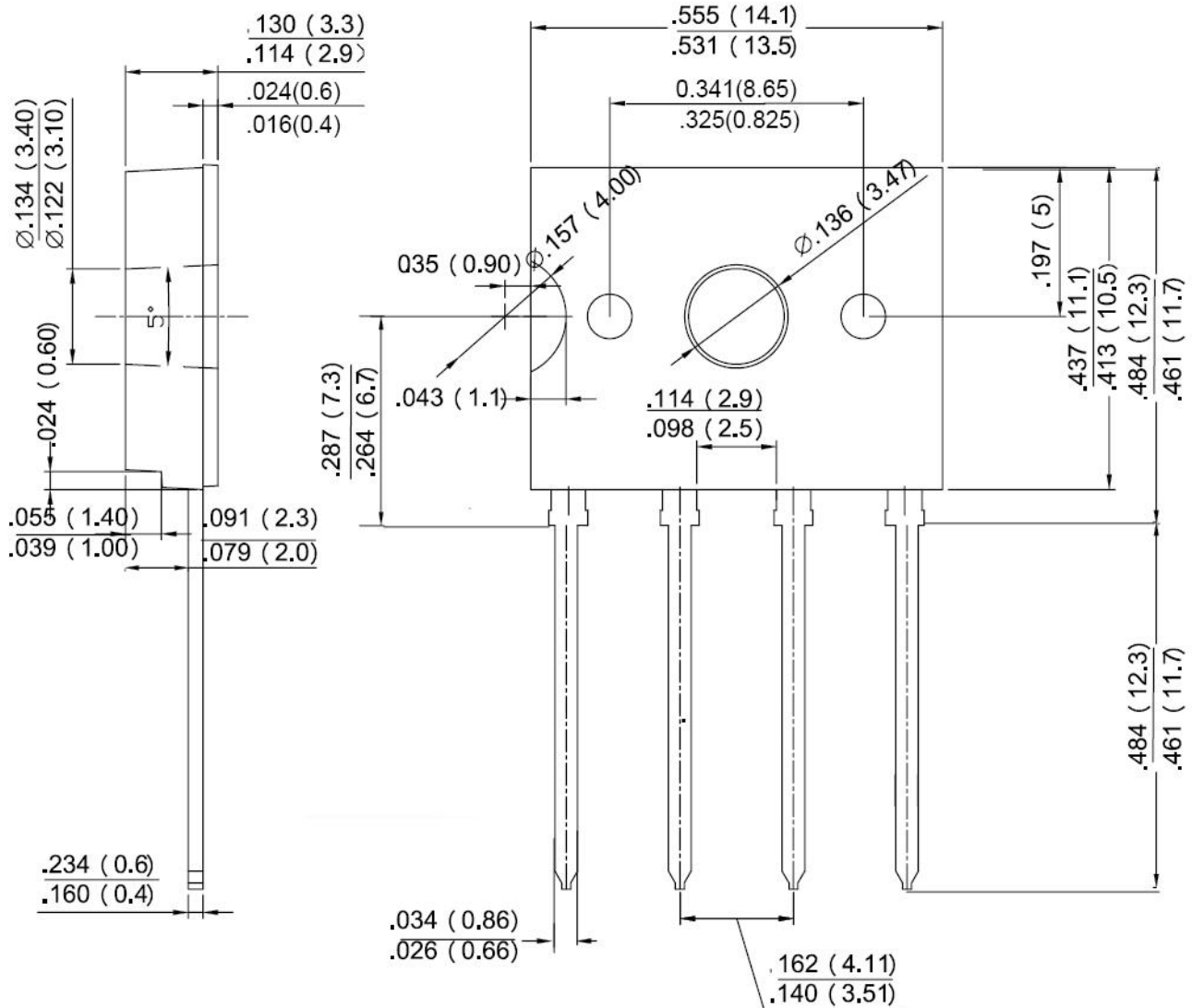


Where XXXXX is YYWWL

SSG = SSG
YY = Year
WW = Week
L = Lot Number
UG4KB05 = Type Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Mechanical Dimensions D3K (Inches/Millimeters)



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- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
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